Supplementary material (ESI) for Journal of Materials Chemistry

Charge Ordering, Symmetry and Electronic Structure Issues and Wigner Crystal Structure of the Quarter-Filled Band Mott Insulators and High Pressure Metals δ-(EDT-TTF-CONMe$_2$)$_2$X, X = Br and AsF$_6$

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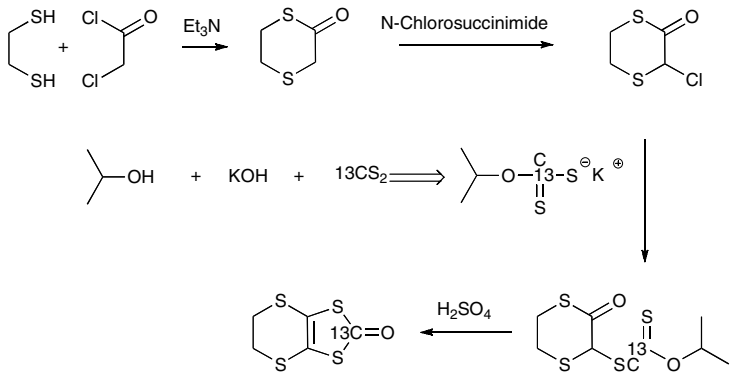
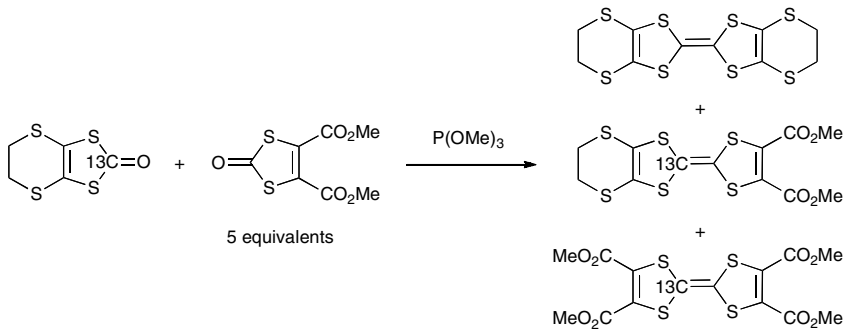
† Electronic Supplementary Information (ESI) available: The Supporting Information includes Schemes S1-S3, Table S1 and the crystallographic information files (CIF). See DOI: 10.1039/b000000x/

Scheme S1. Larsen-Lenoir initial step with $^{13}CS_2$



Scheme S2. Optimized coupling procedure



Scheme S3. Acylchloride and completion of the procedure

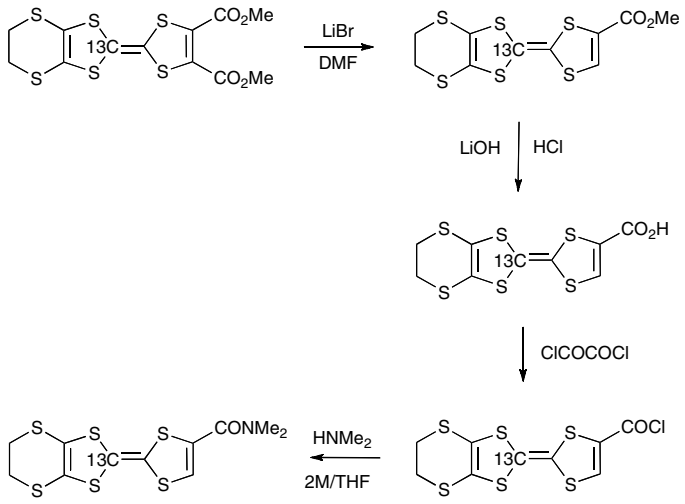


Table S1. Interstack S···S contacts ($r \leq 3.70$ Å) in the conducting layer of δ-(EDT-TTF-$CONMe_2)_2Br$ at room temperature and 150 K

Temperature	Contact distances, Å
150 K	3.2138(7), 3.2724(8), 3.5091(8)
295 K	3.235(1), 3.313(1), 3.519(1)
293 K	3.2317(6), 3.3012(6), 3.5313(6) (interaction C in Fig. 13b)
(double cell)	3.2263(6), 3.3097(6), 3.5174(6) (interaction D in Fig. 13b)